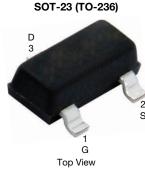
SQ2308FES

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Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET



FEATURES

- TrenchFET[®] Power MOSFET
- AEC-Q101 Qualified
- 100 % $R_{\rm q}$ and UIS Tested
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

N-Channel MOSFET



ROHS COMPLIANT HALOGEN FREE

Marking Code: 9RYXX

PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)}$ (Ω) at V_{GS} = 10 V	0.150			
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.164			
I _D (A)	2.3			
Configuration	Single			

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2308FES-T1_GE3

ABSOLUTE MAXIMUM RATINGS (T _C	= 25 °C, unles	s otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	60	N/	
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current	T _C = 25 °C	- I _D -	2.3		
	T _C = 125 °C		1.3		
Continuous source current (diode conduction)		I _S	2.4	А	
Pulsed drain current ^a		I _{DM}	9		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	7		
Single pulse avalanche energy		E _{AS}	2.5	mJ	
	T _C = 25 °C	– P _D	2	W	
Maximum power dissipation	T _C = 125 °C		0.6	vv	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^b	R _{thJA}	120	°C/W
Junction-to-foot (drain)		R _{thJF}	80	0/10

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. When mounted on 1" square PCB (FR-4 material)

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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static				L		L	L
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		60	-	-	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	- V _{GS} , I _D = 250 μΑ	1.5	2.0	2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V_{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	-	-	50	μA
		V _{GS} = 0 V	V _{DS} = 60 V, T _J = 175 °C	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	10	-	-	Α
		V _{GS} = 10 V	I _D = 2.3 A	-	0.135	0.150	
	-	V _{GS} = 10 V	I _D = 2.3 A, T _J = 125 °C	-	-	0.272	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 2.3 A, T _J = 175 °C	-	-	0.344	Ω
		V _{GS} = 4.5 V	I _D = 2.1 A	-	0.145	0.164	
Forward Transconductance ^b	9 _{fs}	V _{DS} :	= 15 V, I _D = 2.3 A	-	8	-	S
Dynamic ^b		1			1		
Input capacitance	C _{iss}			-	170	205	
Output capacitance	Coss	$V_{GS} = 0 V$	V _{DS} = 30 V, f = 1 MHz	-	25	28	pF
Reverse transfer capacitance	C _{rss}			-	13	18	
Total gate charge ^c	Qg				3.6	5.3	
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 2 \text{ A}$	-	0.7	-	nC
Gate-drain charge ^c	Q _{gd}			-	0.6	-	
Gate resistance	Rg	f = 1 MHz		2.9	5.84	9	Ω
Turn-on delay time ^c	t _{d(on)}	$V_{DD} = 30 \text{ V}, \text{ R}_{\text{L}} = 15 \ \Omega$ $\text{I}_{\text{D}} \cong 2 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \ \Omega$		-	5	6	
Rise time ^c	t _r			-	3	13	
Turn-off delay time ^c	t _{d(off)}			-	10	17	ns
Fall time ^c	t _f			-	2	18	
Source-Drain Diode Ratings and Charact	teristics ^b	1		I	1	I	I
Pulsed current ^a	I _{SM}			-	-	9	Α
Forward voltage	V _{SD}	I _F = 1.6 A, V _{GS} = 0		-	0.82	1.2	V
Body diode reverse recovery time	t _{rr}			-	13	26	ns
Body diode reverse recovery charge	Q _{rr}			-	8	16	nC
Reverse recovery fall time	t _a	IF = 2 /	A, di/dt = 100 A/µs	-	9	-	
Reverse recovery rise time	t _b		-	-	4	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.25	-	Α

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

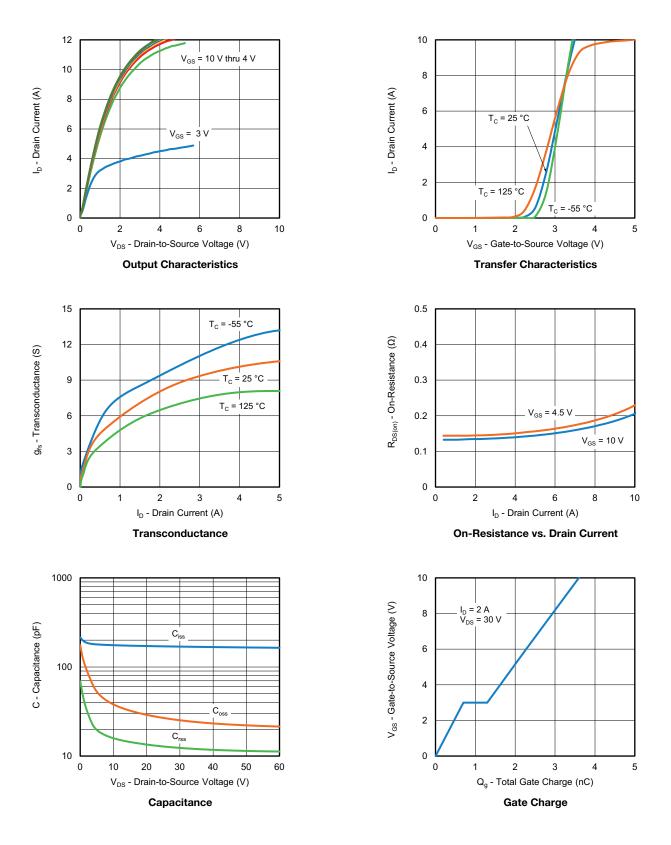
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



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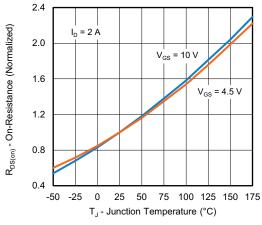
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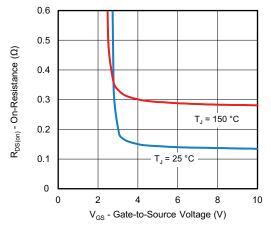


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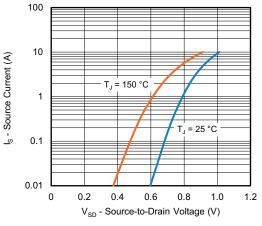
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



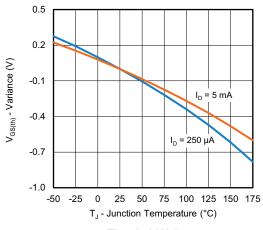
On-Resistance vs. Junction Temperature



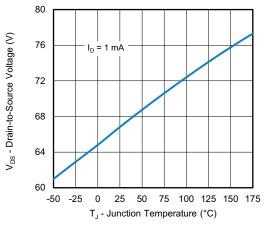
On-Resistance vs. Gate-to-Source Voltage



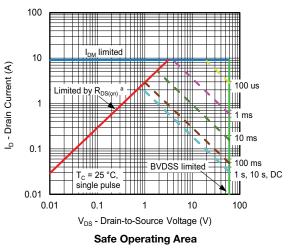
Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature





a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

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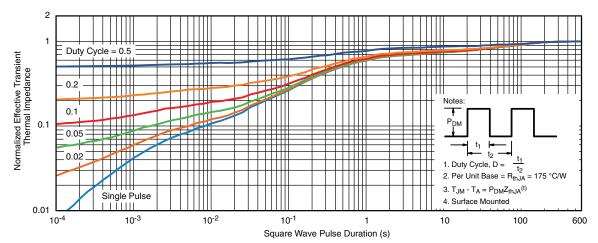
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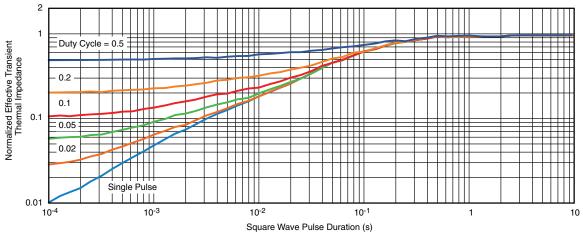


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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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Package Information

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SOT-23 (TO-236): 3-LEAD







Dim —	MILLIN	METERS	INCHES			
	Min	Max	Min	Мах		
Α	0.89	1.12	0.035	0.044		
A ₁	0.01	0.10	0.0004	0.004		
A ₂	0.88	1.02	0.0346	0.040		
b	0.35	0.50	0.014	0.020		
С	0.085	0.18	0.003	0.007		
D	2.80	3.04	0.110	0.120		
E	2.10	2.64	0.083	0.104		
E ₁	1.20	1.40	0.047	0.055		
е	0.95	0.95 BSC		0.0374 Ref		
e ₁	1.90	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024		
L ₁	0.6	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref			
q	3°	8°	3°	8°		



Application Note 826

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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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